

Technical Data Sheet

1.8mm Round Subminiature Chip Phototransistor

Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Package in 12mm tape on 7" diameter reels.
- Pb free
- The product itself will remain within RoHS compliant version.

Descriptions

• PT42-21B/TR8 is a phototransistor in miniature SMD package which is molded in a black plastic with spherical top view lens.

The device is spectrally matched to infrared emitting diode.

Applications

- Miniature switch
- Counters and sorter
- Position sensor
- Infrared applied system

Device Selection Guide

LED Part No.	Chip Material	Lens Color		
PT	Silicon	Black		

PT42-21B/TR8

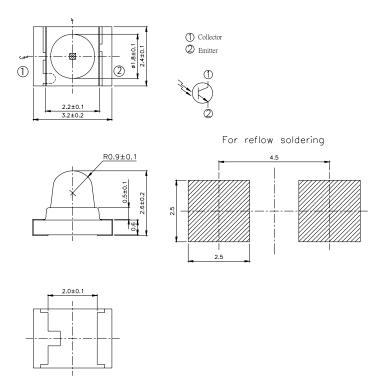


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Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm

Absolute Maximum Ratings (Ta=25 $^{\circ}$ C)

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector-Voltage	V_{ECO}	5	V
Collector Current	I_{C}	20	mA
Operating Temperature	T_{opr}	-25 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	T_{stg}	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Soldering Temperature	T_{sol}	260	$^{\circ}\!\mathbb{C}$
Power Dissipation at(or below)	P_{c}	75	mW
25°C Free Air Temperature			

Notes: *1:Soldering time ≤ 5 seconds.

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Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	bol Condition		Тур	Max	Unit
Rang Of Spectral Bandwidth	λ 0.5		730		1100	nm
Wavelength Of Peak Sensitivity	λ _P			940		nm
Collector-Emitter Breakdown Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_C=100 \mu A$ $Ee=0mW/cm^2$	30			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E=100 \mu A$ $Ee=0 \text{mW/cm}^2$	5			V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =2mA Ee=1m W/cm ²			0.4	V
Collector Dark Current	I_{CEO}	V _{CE} =20V Ee=0mW/cm ²			100	nA
On State Collector Current	$I_{C(ON)}$	$V_{CE}=5V$ $Ee=1mW/cm^2$	1.77	3.0		mA
Rise Time	t _r	V _{CE} =5V		15		
Fall Time	t_{f}	$I_{C}=1 \text{mA}$ $R_{L}=1000 \Omega$		15		μ S

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Typical Electro-Optical Characteristics Curves

Fig.1Collector Power Dissipation vs.

Ambient Temperature

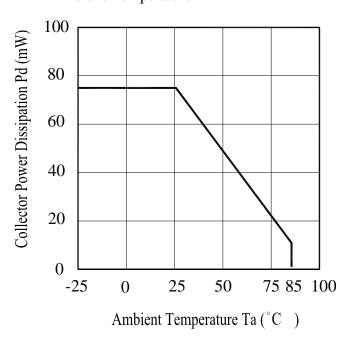


Fig.2 Spectral Sensitivity

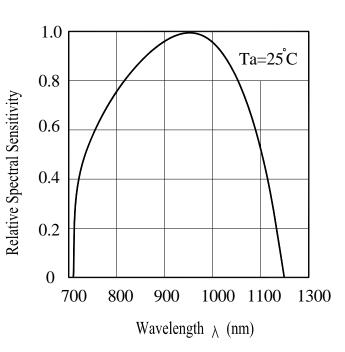


Fig.3 Relative Collector Current vs.

Ambient Temperature

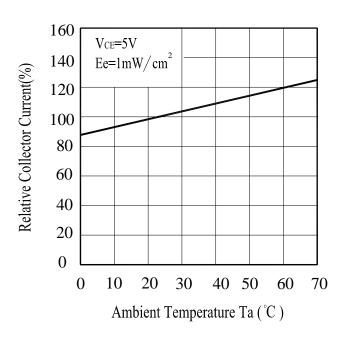
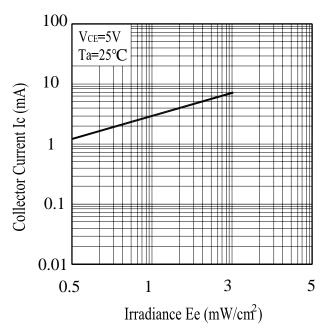


Fig.4 Collector Current vs.
Irradiance



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Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs.

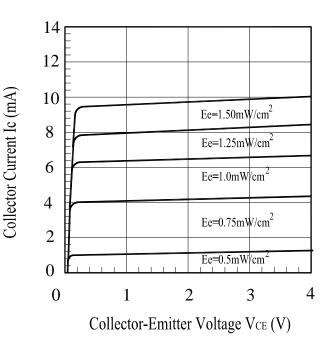
Ambient Temperature

10⁻⁶
5
VCE=20V

10⁻⁷
10⁻⁸
10⁻⁸
5
10⁻⁹
10⁻¹⁰
0
25
50
75
100
Ambient Temperature Ta (°C)

Fig.6 Collector Current vs.

Collector-Emitter Voltage



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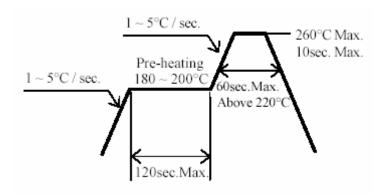
Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

- 2. Storage
 - 2.1 Do not open moisture proof bag before the products are ready to use.
- 2.2 Before opening the package, the LEDs should be kept at 30°C or less and 90%RH or less.
- 2.3 The LEDs should be used within a year.
- 2.4 After opening the package, the LEDs should be kept at 30° C or less and 70%RH or less.
- 2.5 The LEDs should be used within 168 hours (7 days) after opening the package.
- 2.6 If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.

 Baking treatment: 60±5°C for 24 hours.
- 3. Soldering Condition
- 3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the LEDs during heating.
- 3.4 After soldering, do not warp the circuit board.

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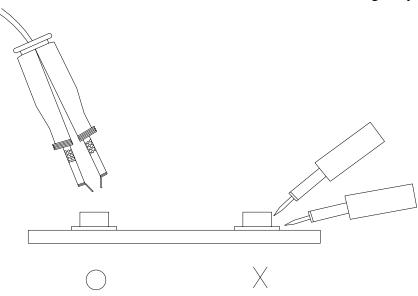


4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 280° C for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5.Repairing

Repair should not be done after the LEDs have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the LEDs will or will not be damaged by repairing.



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Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

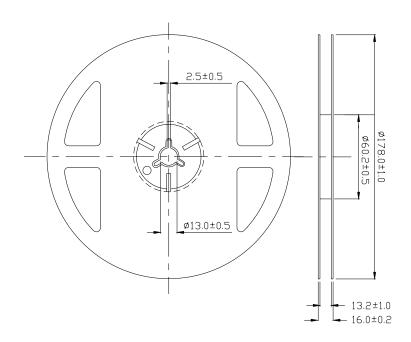
NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	REFLOW	TEMP. : 260°C±5°C	6Mins	22pcs		0/1
		5secs			$I_R \ge U \times 2$	
2	Temperature Cycle	$H: +100^{\circ}C$ 15mins	50Cycles	22pcs	Ee≦Lx0.8	0/1
		5mins			$V_F \ge U \times 1.2$	
		L: -40°C 1 5mins				
3	Thermal Shock	H :+100°C ▲ 5mins	50Cycles	22pcs	U: Upper	0/1
		↓ 10secs	-		Specification	
		L:- 10° C 5mins			Limit	
4	High Temperature	TEMP. : +100°C	1000hrs	22pcs	L: Lower	0/1
	Storage			_	Specification	
5	Low Temperature	TEMP.: -40	1000hrs	22pcs	Limit	0/1
	Storage					
6	DC Operating Life	V _{CE} =5V	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85% R.H	1000hrs	22pcs		0/1
	High Humidity					

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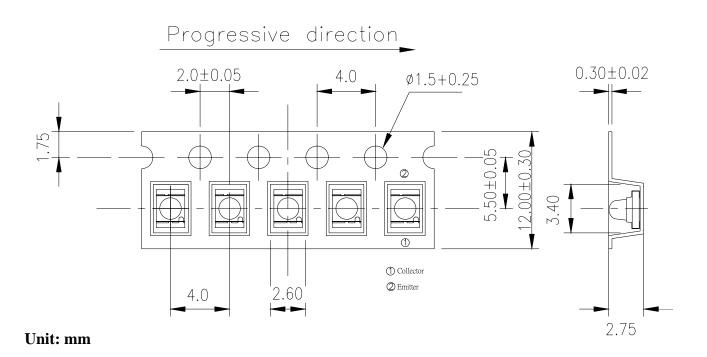
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Package Dimensions



Taping Dimensions



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Packing Quantity Specification

- 1.1000Pcs/1Volume, 1Volume/1Bag
- 2.10Boxes/1Carton

Label Form Specification



CPN: Customer's Production Number

P/N : Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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